74AUP1G240

Low-power inverting buffer/line driver; 3-state

Rev. 5 — 15 March 2019

Product data sheet

1. General description

The 74AUP1G240 provides the single inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (\overline{OE}). A HIGH level at pin \overline{OE} causes the output to assume a high-impedance OFF-state.

This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input $\overline{\text{OE}}$ is HIGH.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- · ESD protection:
 - HBM JESD22-A114F exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- · Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G240GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G240GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm	SOT886				
74AUP1G240GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm	SOT891				
74AUP1G240GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm	SOT1115				
74AUP1G240GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm	SOT1202				
74AUP1G240GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm	SOT1226				

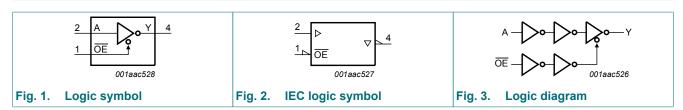
4. Marking

Table 2. Marking

Type number	Marking code[1]
74AUP1G240GW	p2
74AUP1G240GM	p2
74AUP1G240GF	p2
74AUP1G240GN	p2
74AUP1G240GS	p2
74AUP1G240GX	p2

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



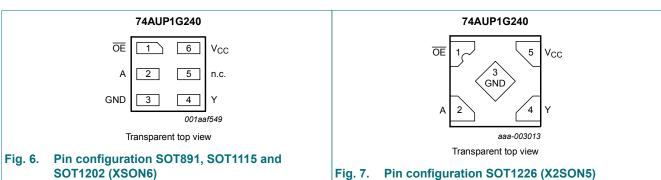
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6. Pinning information

6.1. Pinning





6.2. Pin description

Table 3. Pin description

Symbol	Pin		Description			
	TSSOP5 and X2SON5	XSON6				
ŌĒ	1	1	output enable input			
A	2	2	data input			
GND	3	3	ground (0 V)			
Υ	4	4	data output			
n.c.	-	5	not connected			
V _{CC}	5	6	supply voltage			

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = Don't \ care; \ Z = high-impedance \ OFF-state.$

Input OE		Output
ŌE	A	Υ
L	L	Н
L	Н	L
Н	X	Z

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	5 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V

For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 4.0 mW/K.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
V _{OH} I V _{OL} I I _I i I _{OZ} C I _{OFF} β ΔI _{OFF} δ I _I I _{CC} s		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	V _{CC} - 0.1 - - V 0.75 × V _{CC} - - V 1.11 - - V 1.32 - - V 2.05 - - V 1.9 - - V 2.72 - - V 2.66 - - V - - 0.1 V - - 0.31 V - - 0.31 V - - 0.31 V - - 0.31 V - - 0.44 V - - 0.44 V - - 0.44 V - - ±0.1 μA - - ±0.2 μA - - ±0.2 μA - - - ±0.2 μA - - - ±0.2 μA - - - ±0.2 μ	V		
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	V V V V V V V V V V V V V V - O.31 V - O.31 V - O.31 V - O.31 V - O.44 V - O.31 V - O.44 V - D.44 V - D.5 µ - 40 µ - 110 µ - 1	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-		V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
V_{OL} LOW-like I_{I} input let I_{OZ} OFF-site I_{OFF} power- ΔI_{OFF} addition leakage I_{CC} supply		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	0.75 × V _{CC} - - V 1.11 - - V 2.05 - - V 1.9 - - V 2.72 - - V 2.6 - - V - - 0.1 V - - 0.1 V - - 0.31 V - - 0.44 V - - 0.44 V - - ±0.1 μA - - ±0.1 μA - - ±0.2 μA - - - ±0.2 μA - - - ±0.2 μA - - - - ±0.2 μA - - -	V		
	$I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ 0.3	0.31	V			
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
l _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1] -	-	40	μA
		$\overline{\text{OE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	110	μΑ
		all inputs; V_I = GND to 3.6 V; \overline{OE} = V_{CC} ; V_{CC} = 0.8 V to 3.6 V	[2] -	-	1	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance					
	output enabled	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
	output disabled	V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}	-	1.5	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
V _{IL} In		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	- \\\ - \\\ 0.30 \times \V_{CC} \\\ 0.35 \times \V_{CC} \\\ 0.7 \\\ 0.9 \\\ - \\\\ - \\\\ - \\\\ - \\\\ - \\\\ - \\\\ - \\\\ - \\\\ - \\\\ - \\\\\ - \\\\\ - \\\\\ - \\\\\ - \\\\\ - \\\\\\	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	V V CC V CC V CC V CC V CC V CC V C	V
		V _{CC} = 0.9 V to 1.95 V	-	-		V
		The level input voltage $V_{CC} = 0.8 \text{ V}$ $0.70 \times V_{CC}$ $ 0.70 \times V_{CC}$ $ 0.8 \times V_{CC} = 0.9 \times to 1.95 \times V_{CC} = 0.8 \times V_{CC} = 0.9 \times to 1.95 \times V_{CC} = 0.8 \times V_{CC} = 0.9 \times to 1.95 \times V_{CC} = 0.9 \times V_{CC} = 0.9 \times to 1.95 \times V_{CC} = 0.9 \times$	V			
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}			- 0.35 × V _{CC} V - 0.7 V - 0.9 V O.1 V - 0.3 × V _{CC} V - 0.37 V - 0.35 V	
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
V _{OH} H V _{OL} L I ₁ in I _{OZ} O I _{OFF} p ΔI _{OFF} ar Ie		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	_	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	V V - 0.30 × V _{CC} V - 0.35 × V _{CC} V - 0.7 V - 0.9 V - 0.9 V - O.37 V - O.35 V - O.45 V - O.33 V - O.45 V - D.45 V - D.5	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	_	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OI}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	_	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
			-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		$I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	_	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	_	0.45	V
I _I	input leakage current	$V_1 = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
l _{OZ}	OFF-state output current		-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	-	-	50	μA
		\overline{OE} input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	120	μA
		all inputs; V_I = GND to 3.6 V; \overline{OE} = V_{CC} ; V_{CC} = 0.8 V to 3.6 V	2] -	-	1	μA

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V		0.75 × V _{CC}	-	-	V
V _{IH} H V _{IL} L V _{OL} L I _I ir I _{OFF} p ΔI _{OFF} a I _E a I _{OFF} a I _E a		V _{CC} = 0.9 V to 1.95 V		0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V		-	-		V
		V _{CC} = 0.9 V to 1.95 V	8 V 0.75 × V _{CC} V 9 V to 1.95 V 0.70 × V _{CC} V 0.70 × 0.86 V 0.70 × V _{CC} V 0.70 × 0.70 × V _{CC} V 0.70 × 0.70 × V _{CC} V 0.70 × 0.70	V			
		V _{CC} = 2.3 V to 2.7 V		V			
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				- 0.9 \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ - 0.33 \times \text{Vcc} \\	
		$\begin{split} &I_O = -1.1 \text{ mA; } V_{CC} = 1.1 \text{ V} & 0.6 \times V_{CC} & - & - & \text{V} \\ &I_O = -1.7 \text{ mA; } V_{CC} = 1.4 \text{ V} & 0.93 & - & - & \text{V} \\ &I_O = -1.9 \text{ mA; } V_{CC} = 1.65 \text{ V} & 1.17 & - & - & \text{V} \\ &I_O = -2.3 \text{ mA; } V_{CC} = 2.3 \text{ V} & 1.77 & - & - & \text{V} \\ &I_O = -3.1 \text{ mA; } V_{CC} = 2.3 \text{ V} & 1.67 & - & - & \text{V} \\ &I_O = -2.7 \text{ mA; } V_{CC} = 3.0 \text{ V} & 2.40 & - & - & \text{V} \\ \end{split}$					
Voh F		I _O = -1.1 mA; V _{CC} = 1.1 V		0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.17	-	V	
		I _O = -2.3 mA; V _{CC} = 2.3 V		1.77	-	V V CC V V CC V CC V CC V CC V CC V	V
				1.67	-		V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V		2.40	-	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V		-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-		
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.50	V
l ₁	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V		-	-	±0.75	μA
	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.75	
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$		-	-	±0.75	μA
	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V		-	-	±0.75	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V		-	-	1.4	μΑ
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	75	μA
		$\overline{\text{OE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	180	μA
		all inputs; V_I = GND to 3.6 V; \overline{OE} = V_{CC} ; V_{CC} = 0.8 V to 3.6 V	[2]	-	-	1	μA

 $[\]begin{tabular}{ll} [1] & One input at V_{CC} - 0.6 V, other input at V_{CC} or GND. \\ [2] & To show I_{CC} remains very low when the input-disable feature is enabled. \\ \end{tabular}$

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10

Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
				Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 p	F	,	_	<u>'</u>	'				
t _{pd}	propagation delay	A to Y; see Fig. 8	2]						
		V _{CC} = 0.8 V	-	22.3	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	5.8	12.6	2.8	14.1	15.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.0	7.3	2.1	8.5	9.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.2	5.5	1.9	6.7	7.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.6	4.1	1.5	4.8	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.3	3.6	1.3	4.1	4.6	ns
t _{en}	enable time	OE to Y; see Fig. 9	3]						
		V _{CC} = 0.8 V	-	70.2	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	6.4	14.3	2.8	15.9	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.4	8.1	2.2	9.5	10.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.6	6.2	1.9	7.4	8.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.8	4.6	1.7	5.4	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.5	4.0	1.7	4.7	5.3	ns
t _{dis}	disable time	OE to Y; see Fig. 9	4]						
		V _{CC} = 0.8 V	-	14.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.0	4.3	7.4	2.3	8.3	9.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.6	3.2	5.2	1.7	5.9	6.5	ns
		V _{CC} = 1.65 V to 1.95 V	1.5	3.0	4.8	1.5	5.5	6.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.2	3.5	1.4	4.0	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.5	3.9	1.4	4.5	5.0	ns
C _L = 10	ρF								
t _{pd}	propagation delay	A to Y; see Fig. 8	2]						
		V _{CC} = 0.8 V	-	25.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	6.6	14.5	3.2	16.3	18.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.4	2.0	9.9	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.8	6.4	1.8	7.7	8.6	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.1	4.8	1.7	5.7	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.8	4.3	1.7	5.0	5.5	ns
t _{en}	enable time	OE to Y; see Fig. 9	3]						
		V _{CC} = 0.8 V	-	74.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.4	16.3	3.2	18.2	20.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	5.1	9.2	2.1	10.9	12.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	4.1	7.1	1.8	8.5	9.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	5.4	1.7	6.4	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.1	4.8	1.7	5.7	6.3	ns

Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	OE to Y; see Fig. 9 [4]							
		V _{CC} = 0.8 V	-	33.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	5.4	9.0	3.2	10.0	11.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.1	6.3	2.1	7.1	7.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.2	6.3	1.8	7.1	7.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	3.0	4.6	1.7	5.2	5.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.8	5.7	1.7	6.4	7.1	ns
C _L = 15	p F			1				'	
t _{pd}	propagation delay	A to Y; see Fig. 8 [2]							
		V _{CC} = 0.8 V	-	29.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	7.4	16.3	3.6	18.4	20.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	9.4	2.5	11.1	12.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.2	7.2	2.1	8.7	9.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.5	5.4	1.9	6.5	7.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.3	4.9	1.9	5.7	6.4	ns
t _{en}	enable time	OE to Y; see Fig. 9 [3							
		V _{CC} = 0.8 V	-	77.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	8.2	18.2	3.6	20.4	22.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.6	10.3	2.5	12.2	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.6	7.9	2.1	9.5	10.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.9	6.0	2.0	7.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.6	5.5	1.9	6.4	7.1	ns
t _{dis}	disable time	OE to Y; see Fig. 9 [4							
		V _{CC} = 0.8 V	-	62.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.6	10.4	3.6	11.6	12.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	7.4	2.5	8.4	9.3	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	7.8	2.1	8.7	9.7	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	5.7	2.0	6.4	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	5.0	7.4	1.9	8.3	9.1	ns
C _L = 30	ρF							1	
t _{pd}	propagation delay	A to Y; see Fig. 8 [2]							
•		V _{CC} = 0.8 V	-	39.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.0	9.7	21.6	4.6	24.3	26.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	12.3	3.0	14.6	16.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.5	9.5	2.7	11.5	12.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.6	7.1	2.5	8.6	9.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	4.3	6.4	2.5	7.7	8.5	ns

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Symbol	Parameter	Conditions		25 °C		-40 °C to +125 °C			Unit
			Min	Min Typ[1]		Min	Max Max (85 °C) (125 °C)		
t _{en}	enable time	OE to Y; see Fig. 9]						
		V _{CC} = 0.8 V	-	89.4	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	10.6	23.8	4.6	26.7	29.5	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	7.3	13.2	3.0	15.7	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	6.0	10.2	2.7	12.3	13.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.8	5.0	7.8	2.6	9.3	10.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	4.8	7.1	2.6	8.4	9.3	ns
t _{dis}	disable time	OE to Y; see Fig. 9 [4]						
		V _{CC} = 0.8 V	-	68.9	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.3	15.0	4.6	16.5	18.2	ns
		V _{CC} = 1.4 V to 1.6 V	4.4	7.7	11.0	3.0	12.2	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	5.1	8.8	12.4	2.7	13.7	15.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	6.2	9.0	2.6	10.0	11.0	ns
		V _{CC} = 3.0 V to 3.6 V	5.2	8.8	12.7	2.6	14.0	15.4	ns
C _L = 5 pl	F, 10 pF, 15 pF and	30 pF	'	1		'	'		
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ [5] $V_I = \text{GND to V}_{CC}$]						
		V _{CC} = 0.8 V	-	2.7	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- [2] [3] t_{pd} is the same as t_{PLH} and t_{PHL} t_{en} is the same as t_{PZH} and t_{PZL}
- t_{dis} is the same as t_{PZH} and t_{PZ}
 t_{dis} is the same as t_{PHZ} and t_{PLZ}
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} x V_{CC}² x f_i x N + Σ(C_L x V_{CC}² x f_o) where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

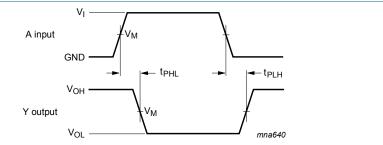
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

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11.1. Waveforms and test circuit



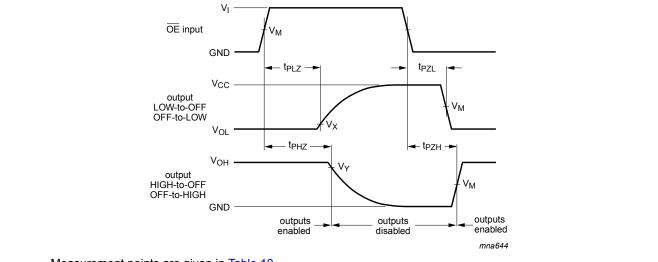
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig. 8. The data input (A) to output (Y) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	V _I	$t_r = t_f$
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns



Measurement points are given in Table 10.

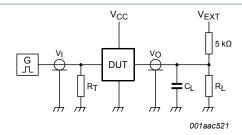
Logic levels: V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig. 9. Enable and disable time

Table 10. Measurement points

Supply voltage	Input	Output			
V _{CC}	V _M	V _M	V _X	V _Y	
0.8 V to 1.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V	
1.65 V to 2.7 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V	
3.0 V to 3.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V	

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Test data is given in Table 11.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 10. Test circuit for measuring switching times

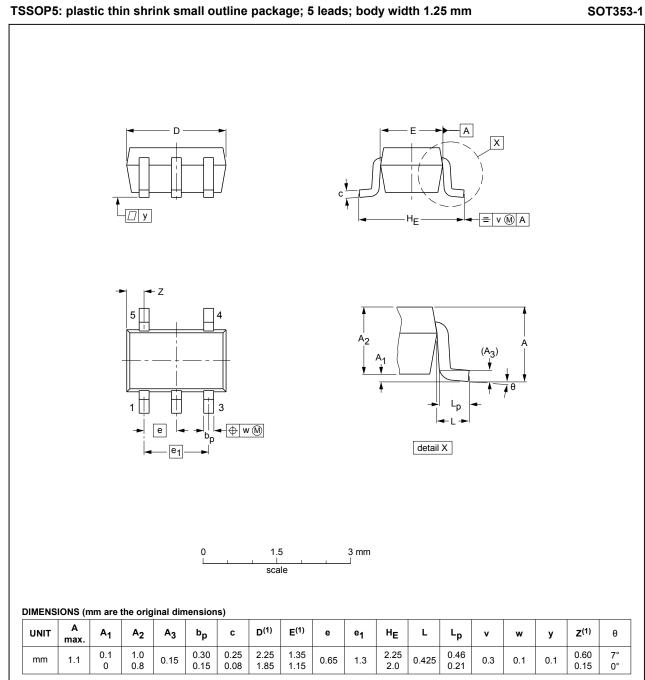
Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 x V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Package outline



Noto

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

	OUTLINE	REFERENCES			EUROPEAN ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA			ISSUE DATE
	SOT353-1		MO-203	SC-88A		$ \ \ \bigoplus \big($	-00-09-01 03-02-19

Fig. 11. Package outline SOT353-1 (TSSOP5)

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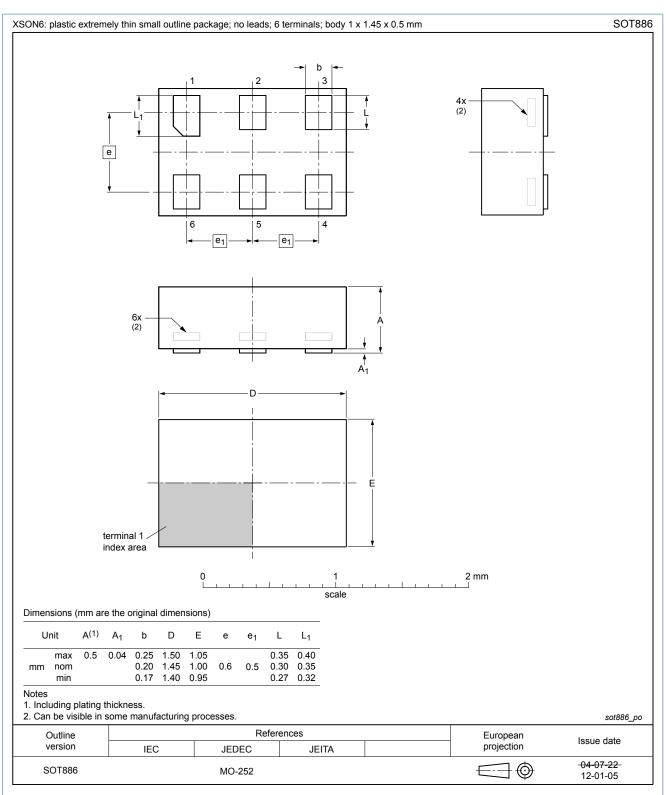


Fig. 12. Package outline SOT886 (XSON6)

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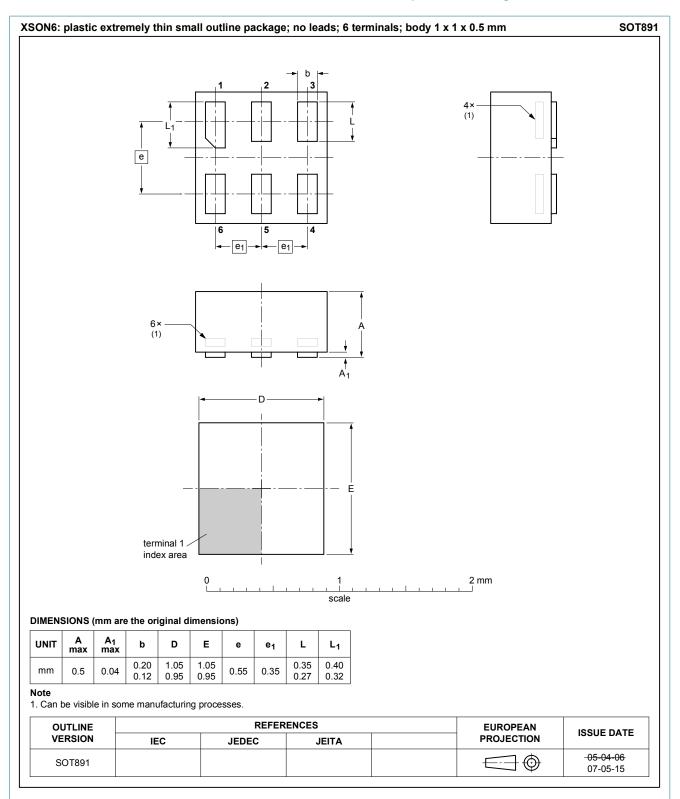


Fig. 13. Package outline SOT891 (XSON6)

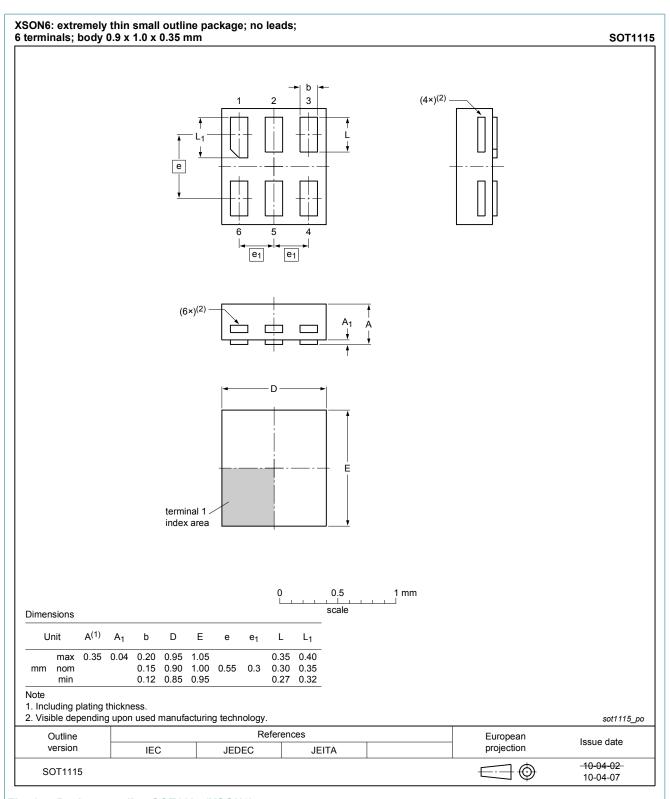


Fig. 14. Package outline SOT1115 (XSON6)

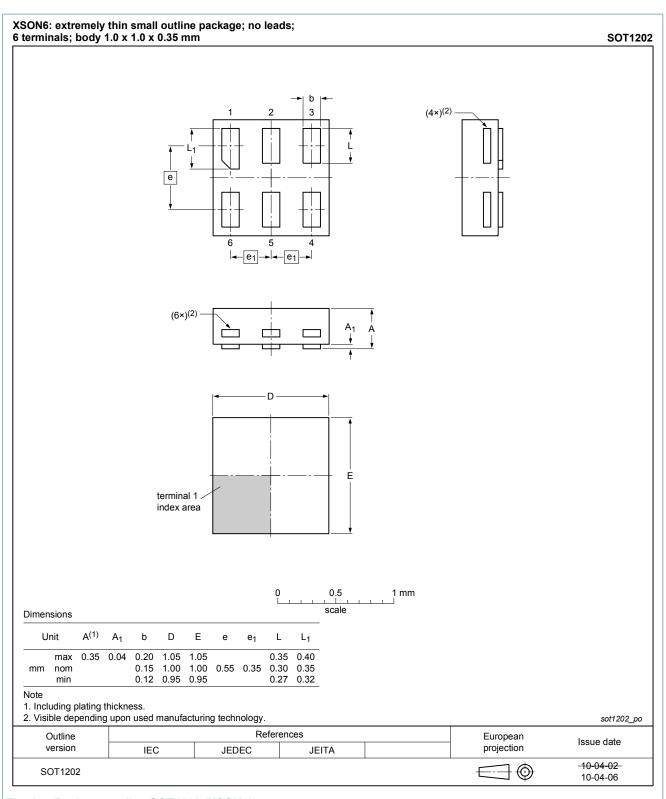


Fig. 15. Package outline SOT1202 (XSON6)

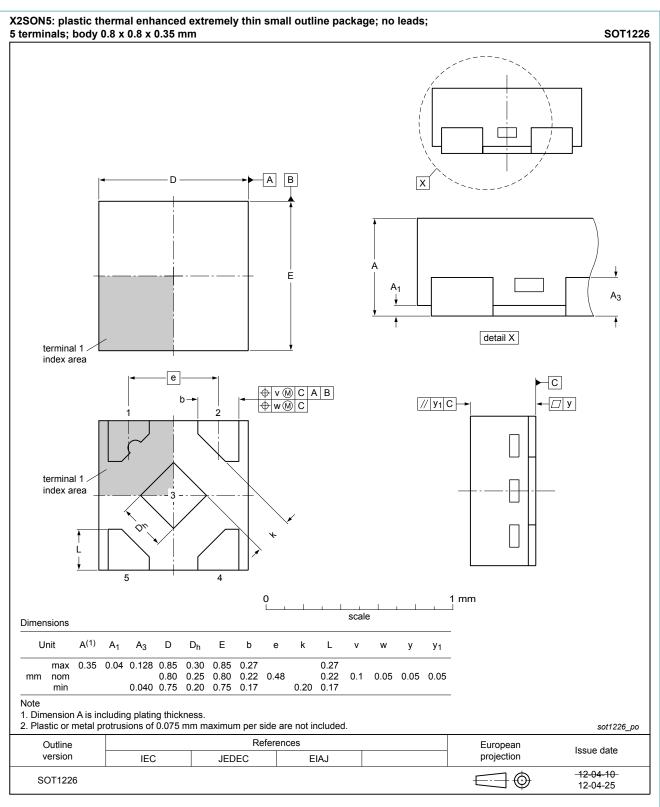


Fig. 16. Package outline SOT1226 (X2SON5)

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13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G240 v.5	20190315	Product data sheet	-	74AUP1G240 v.4
Nexperia		this data sheet has been redove been adapted to the new		, ,
74AUP1G240 v.4	20120629	Product data sheet	-	74AUP1G240 v.3
Modifications: • Added type number 74AUP1G240GX (SOT1: • Package outline drawing of SOT886 (Fig. 12)		,		
74AUP1G240 v.3	20111124	Product data sheet	-	74AUP1G240 v.2
Modifications:	Legal pages u	pdated.		,
74AUP1G240 v.2	20100913	Product data sheet	-	74AUP1G240 v.1
74AUP1G240 v.1	20061106	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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